

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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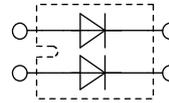
Sonic Fast Recovery Diode

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Parallel legs

$V_{RRM} = 1200\text{ V}$
 $I_{FAV} = 2 \times 25\text{ A}$
 $t_{rr} = 200\text{ ns}$

Part number

DHG 50 X 1200 NA



Backside: Isolated

E72873

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

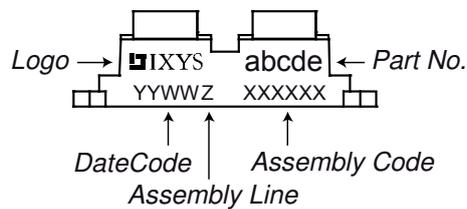
Package:

- Housing: SOT-227B (minibloc)
- Industry standard outline
- Cu base plate internal DCB isolated
- Isolation Voltage 3000 V
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

Symbol	Definition	Conditions	Ratings			Unit	
			min.	typ.	max.		
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25\text{ }^{\circ}\text{C}$			1200	V	
I_R	reverse current	$V_R = 1200\text{ V}$			30	μA	
		$V_R = 1200\text{ V}$			0.5	mA	
V_F	forward voltage	$I_F = 25\text{ A}$			2.11	V	
		$I_F = 50\text{ A}$			2.74	V	
		$I_F = 25\text{ A}$	$T_{VJ} = 125\text{ }^{\circ}\text{C}$			2.09	V
		$I_F = 50\text{ A}$	$T_{VJ} = 125\text{ }^{\circ}\text{C}$			2.88	V
I_{FAV}	average forward current	rectangular $d = 0.5$	$T_C = 65\text{ }^{\circ}\text{C}$		25	A	
V_{F0}	threshold voltage	} for power loss calculation only	$T_{VJ} = 150\text{ }^{\circ}\text{C}$		1.23	V	
r_F	slope resistance				30	m Ω	
R_{thJC}	thermal resistance junction to case				1.20	K/W	
T_{VJ}	virtual junction temperature		-40		150	$^{\circ}\text{C}$	
P_{tot}	total power dissipation		$T_C = 25\text{ }^{\circ}\text{C}$		100	W	
I_{FSM}	max. forward surge current	$t = 10\text{ ms}$ (50 Hz), sine	$T_{VJ} = 45\text{ }^{\circ}\text{C}$		200	A	
I_{RM}	max. reverse recovery current		$T_{VJ} = 25\text{ }^{\circ}\text{C}$		23	A	
		$I_F = 30\text{ A}; V_R = 600\text{ V}$	$T_{VJ} = 125\text{ }^{\circ}\text{C}$		30	A	
t_{rr}	reverse recovery time	$-di_F/dt = 600\text{ A}/\mu\text{s}$	$T_{VJ} = 25\text{ }^{\circ}\text{C}$		200	ns	
			$T_{VJ} = 125\text{ }^{\circ}\text{C}$		350	ns	
C_J	junction capacitance	$V_R = 600\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25\text{ }^{\circ}\text{C}$		11	pF	

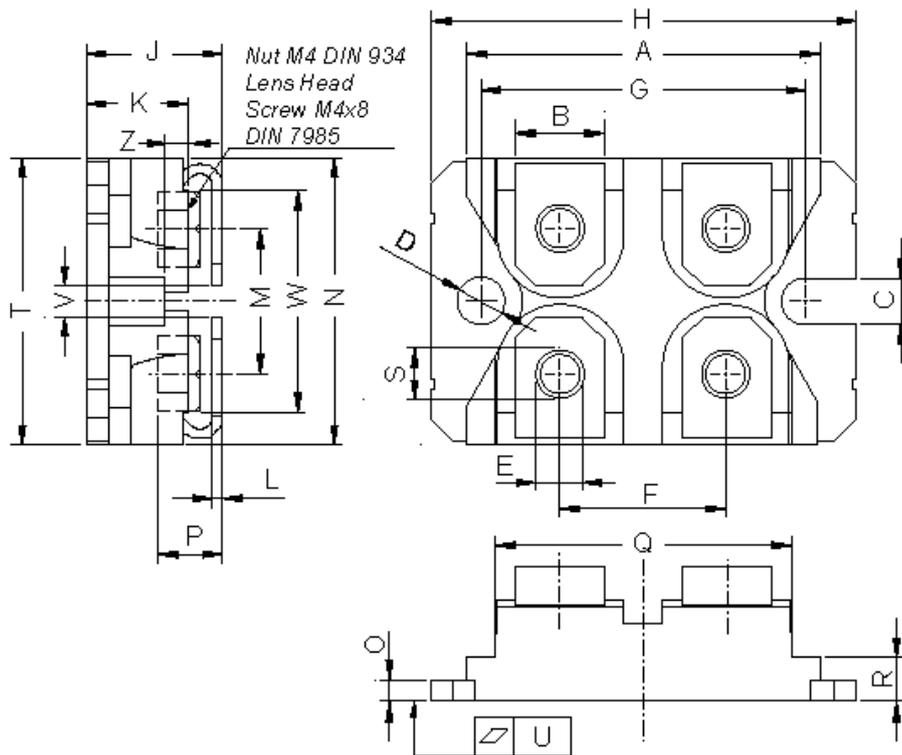
Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			100	A
R_{thCH}	thermal resistance case to heatsink			0.10		K/W
T_{stg}	storage temperature		-40		150	°C
Weight				30		g
M_D	mounting torque		1.1		1.5	Nm
M_T	terminal torque		1.1		1.5	Nm
V_{ISOL}	isolation voltage	t = 1 second	3000			V
		t = 1 minute	2500			V
$d_{Spp/App}$	creepage / striking distance on surface / through air	terminal to terminal	10.5	3.2		mm
$d_{Spb/Apb}$	creepage / striking distance on surface / through air	terminal to backside	8.6	6.8		mm

Product Marking

Part number

D = Diode
 H = Sonic Fast Recovery Diode
 G = extreme fast
 50 = Current Rating [A]
 X = Parallel legs
 1200 = Reverse Voltage [V]
 NA = SOT-227B (minibloc)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DHG 50 X 1200 NA	DHG50X1200NA	Tube	10	507766

Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106

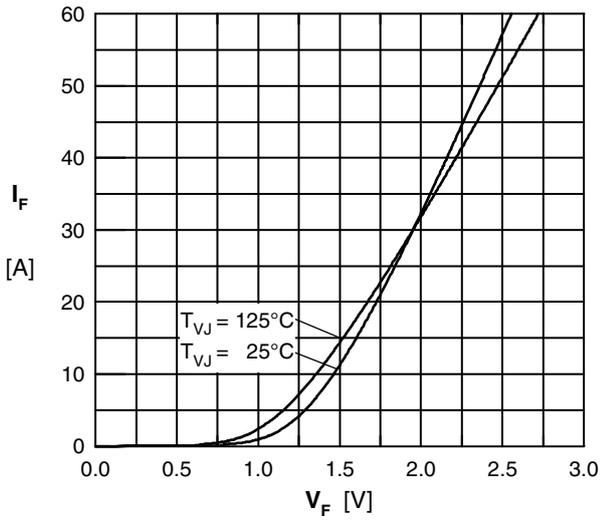


Fig. 1 Typ. Forward current versus V_F

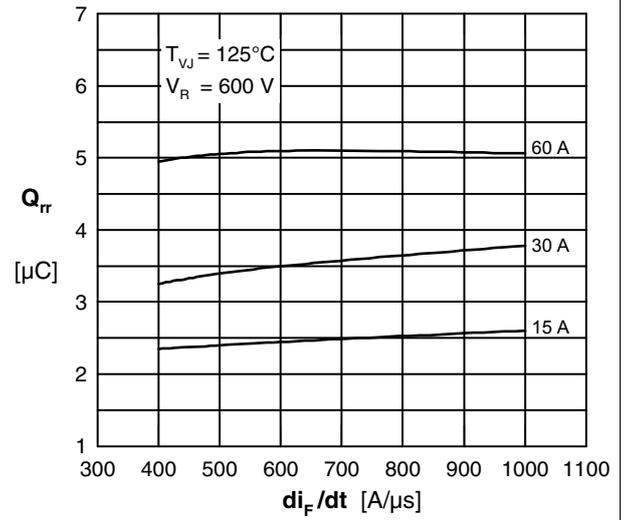


Fig. 2 Typ. reverse recov.charge Q_{rr} vs. di/dt

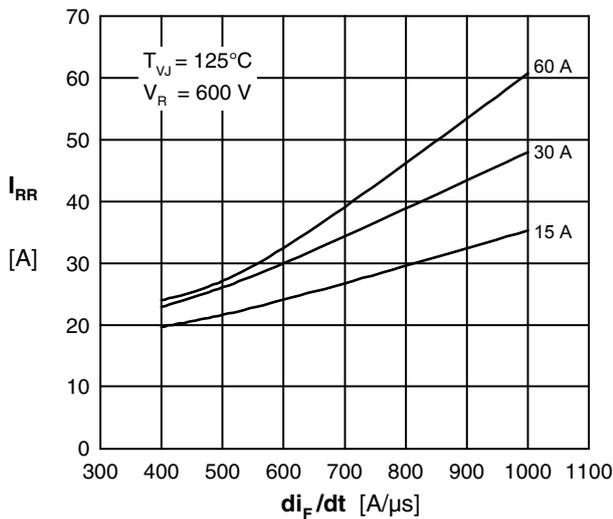


Fig. 3 Typ. peak reverse current I_{RM} vs. di/dt

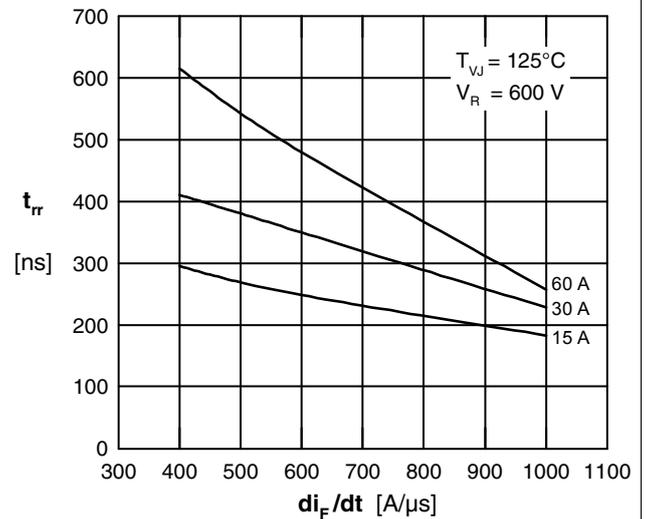


Fig. 4 Typ. recovery time t_{rr} versus di/dt

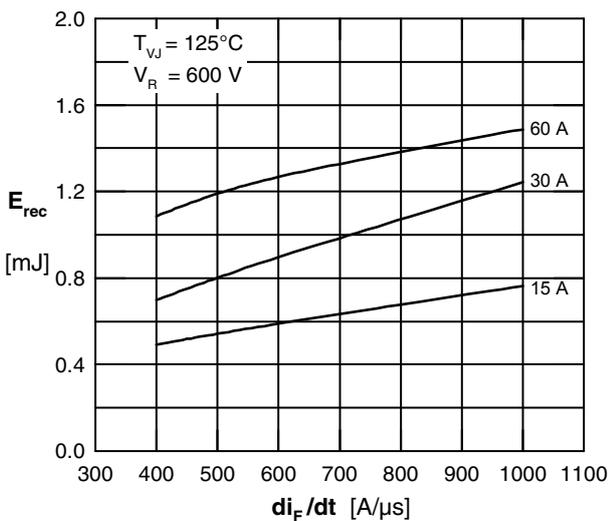


Fig. 5 Typ. recovery energy E_{rec} versus di/dt

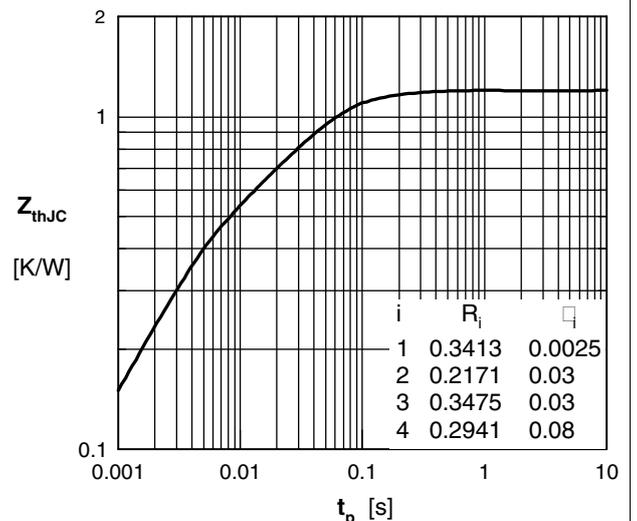


Fig. 6 Typ. transient thermal impedance